



Table 1. Quick reference data ...continued

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Dynamic	characteristics					
Q_{GD}	gate-drain charge	$V_{GS} = 4.5 \text{ V}; I_D = 20 \text{ A};$ $V_{DS} = 15 \text{ V}; \text{ see } \frac{\text{Figure 14}}{\text{Figure 15}};$	-	2.5	-	nC
$Q_{G(tot)}$	total gate charge	$V_{GS} = 4.5 \text{ V}; I_D = 20 \text{ A};$ $V_{DS} = 15 \text{ V}; \text{ see } \frac{\text{Figure 14}}{\text{Figure 15}};$	-	7.9	-	nC

2. Pinning information

Table 2. Pinning information

		,				
Pin	Symbol	Description	Simplified outline	Graphic symbol		
1	S	source		_		
2	S	source	mb	D		
3	S	source		$G \longrightarrow A$		
4	G	gate	[O]			
mb	D	mounting base; connected to drain	1 2 3 4	mbb076 S		
			SOT669 (LFPAK; Power-SO8)			

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PSMN7R0-30YLC	LFPAK; Power-SO8	plastic single-ended surface-mounted package; 4 leads	SOT669



4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C	-	30	V
V_{DGR}	drain-gate voltage	25 °C \leq T _j \leq 175 °C; R _{GS} = 20 k Ω	-	30	V
V_{GS}	gate-source voltage		-20	20	V
I _D	drain current	$V_{GS} = 10 \text{ V; } T_{mb} = 25 \text{ °C; see } \frac{\text{Figure 1}}{\text{Model}}$	-	61	Α
		$V_{GS} = 10 \text{ V; } T_{mb} = 100 \text{ °C; see } \frac{\text{Figure 1}}{}$	-	43	Α
I _{DM}	peak drain current	pulsed; $t_p \le 10 \mu s$; $T_{mb} = 25 \text{ °C}$; see Figure 4	-	245	Α
P _{tot}	total power dissipation	T _{mb} = 25 °C; see <u>Figure 2</u>	-	48	W
T _{stg}	storage temperature		-55	175	°C
Tj	junction temperature		-55	175	°C
T _{sld(M)}	peak soldering temperature		-	260	°C
V _{ESD}	electrostatic discharge voltage	MM (JEDEC JESD22-A115)	190	-	V
Source-drai	n diode				
Is	source current	T _{mb} = 25 °C	-	44	Α
I _{SM}	peak source current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$	-	245	Α
Avalanche r	uggedness				
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; I_D = 61 A; $V_{sup} \le$ 30 V; R_{GS} = 50 Ω; unclamped; see Figure 3	-	15	mJ

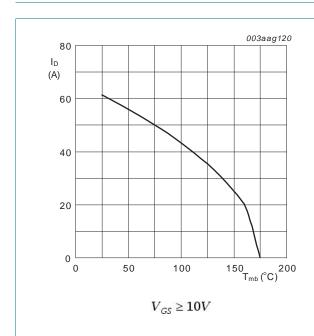
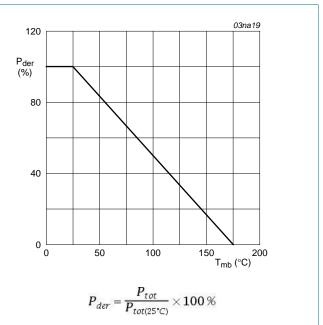


Fig 1. Continuous drain current as a function of mounting base temperature

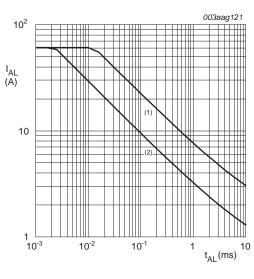


ig 2. Normalized total power dissipation as a function of mounting base temperature

PSMN7R0-30YLC

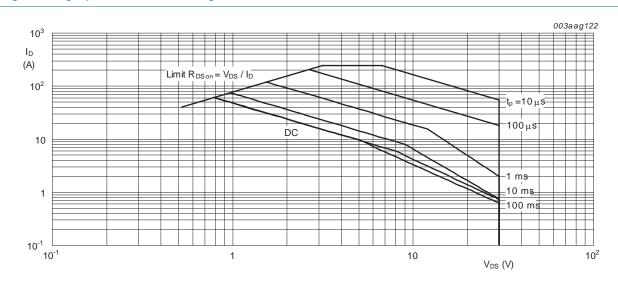
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(1) $T_{j (init)} = 25^{\circ}C$; (2) $T_{j (init)} = 100^{\circ}C$

Fig 3. Single pulse avalanche rating; avalanche current as a function of avalanche time



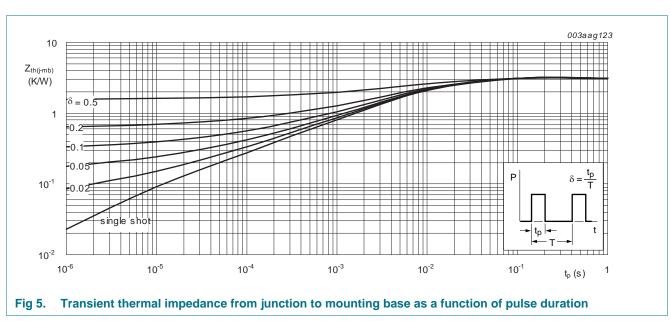
 $T_{mb} = 25$ °C; I_{DM} is a single pulse

Fig 4. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	see Figure 5	-	2.9	3.13	K/W



6. Characteristics

Table 6 Characteristics

Table 6.	Characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
V _{(BR)DSS}	drain-source breakdown	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 °C$	30	-	-	V
	voltage	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = -55 °C$	27	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$I_D = 1$ mA; $V_{DS} = V_{GS}$; $T_j = 25$ °C; see <u>Figure 10</u>	1.05	1.58	1.95	V
		I_D = 10 mA; V_{DS} = V_{GS} ; T_j = 150 °C; see <u>Figure 11</u>	0.5	-	-	V
		$I_D = 1$ mA; $V_{DS} = V_{GS}$; $T_j = -55$ °C; see Figure 11	-	-	2.35	V
I _{DSS}	drain leakage current	$V_{DS} = 30 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	-	1	μΑ
		$V_{DS} = 30 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 150 \text{ °C}$	-	-	100	μΑ
I _{GSS}	gate leakage current	$V_{GS} = 16 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	-	100	nA
		$V_{GS} = -16 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	-	100	nA
200	drain-source on-state resistance	$V_{GS} = 4.5 \text{ V}; I_D = 20 \text{ A}; T_j = 25 \text{ °C};$ see Figure 12	-	7.6	8.9	mΩ
		$V_{GS} = 4.5 \text{ V}; I_D = 20 \text{ A}; T_j = 150 °C;$ see Figure 12; see Figure 13	-	-	14.7	mΩ
		$V_{GS} = 10 \text{ V}; I_D = 20 \text{ A}; T_j = 25 \text{ °C};$ see Figure 12	-	6	7.1	mΩ
		$V_{GS} = 10 \text{ V}; I_D = 20 \text{ A}; T_j = 150 ^{\circ}\text{C};$ see Figure 12; see Figure 13	-	-	11.8	mΩ
R_G	gate resistance	f = 1 MHz	-	2.2	4.4	Ω
Dynamic (characteristics					
Q _{G(tot)}	total gate charge	$I_D = 20 \text{ A}$; $V_{DS} = 15 \text{ V}$; $V_{GS} = 10 \text{ V}$; see Figure 14; see Figure 15	-	16	-	nC
		$I_D = 20 \text{ A}$; $V_{DS} = 15 \text{ V}$; $V_{GS} = 4.5 \text{ V}$; see Figure 14; see Figure 15	-	7.9	-	nC
		$I_D = 0 \text{ A}$; $V_{DS} = 0 \text{ V}$; $V_{GS} = 10 \text{ V}$; see <u>Figure 15</u>	-	14	-	nC
Q_{GS}	gate-source charge	$I_D = 20 \text{ A}; V_{DS} = 15 \text{ V}; V_{GS} = 4.5 \text{ V};$	-	2.7	-	nC
Q _{GS(th)}	pre-threshold gate-source charge	see <u>Figure 14;</u> see <u>Figure 15</u>	-	1.7	-	nC
Q _{GS(th-pl)}	post-threshold gate-source charge		-	1	-	nC
Q _{GD}	gate-drain charge		-	2.5	-	nC
V _{GS(pl)}	gate-source plateau voltage	$I_D = 20 \text{ A}$; $V_{DS} = 15 \text{ V}$; see <u>Figure 14</u> ; see <u>Figure 15</u>	-	2.77	-	V
C _{iss}	input capacitance	V _{DS} = 15 V; V _{GS} = 0 V; f = 1 MHz;	-	1057	-	pF
C _{oss}	output capacitance	T _j = 25 °C; see <u>Figure 16</u>	-	235	-	pF
C _{rss}	reverse transfer capacitance		-	77	-	pF

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Table 6. Characteristics ... continued

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$t_{d(on)}$	turn-on delay time	$V_{DS} = 15 \text{ V}; R_L = 0.75 \Omega; V_{GS} = 4.5 \text{ V};$	-	15	-	ns
t _r	rise time	$R_{G(ext)} = 4.7 \Omega$	-	18	-	ns
$t_{d(off)}$	turn-off delay time		-	20	-	ns
t _f	fall time		-	7.5	-	ns
Q _{oss}	output charge	$V_{GS} = 0 \text{ V}; V_{DS} = 15 \text{ V}; f = 1 \text{ MHz};$ $T_j = 25 \text{ °C}$	-	6.4	-	nC
Source-drain	n diode					
V _{SD}	source-drain voltage	$I_S = 20 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C};$ see Figure 17	-	0.86	1.1	V
t _{rr}	reverse recovery time	$I_S = 20 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s};$	-	25	-	ns
Q _r	recovered charge	$V_{GS} = 0 \text{ V}; V_{DS} = 15 \text{ V}$	-	13	-	nC
t _a	reverse recovery rise time	$V_{GS} = 0 \text{ V; } I_S = 20 \text{ A;}$ $dI_S/dt = -100 \text{ A/}\mu\text{s; } V_{DS} = 15 \text{ V;}$ see Figure 18	-	16	-	ns
t _b	reverse recovery fall time		-	9	-	ns

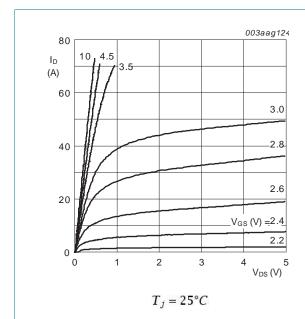


Fig 6. Output characteristics; drain current as a function of drain-source voltage; typical values

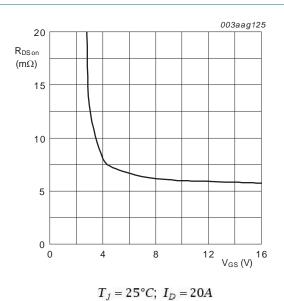
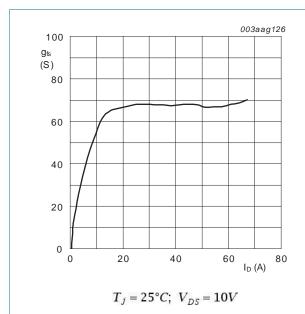


Fig 7. Drain-source on-state resistance as a function of gate-source voltage; typical values



Forward transconductance as a function of Fig 8. drain current; typical values

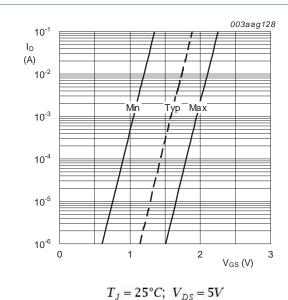


Fig 10. Sub-threshold drain current as a function of gate-source voltage

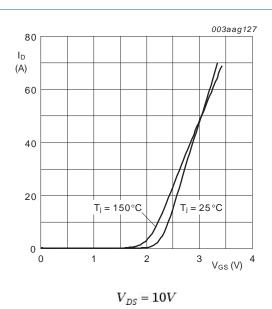


Fig 9. Transfer characteristics; drain current as a function of gate-source voltage; typical values

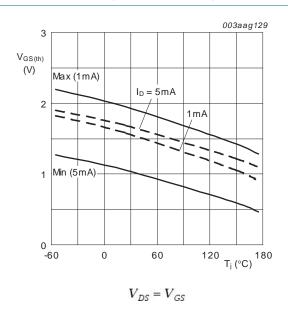


Fig 11. Gate-source threshold voltage as a function of junction temperature

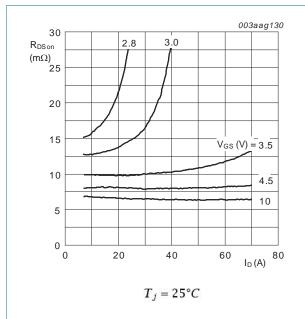


Fig 12. Drain-source on-state resistance as a function of drain current; typical values

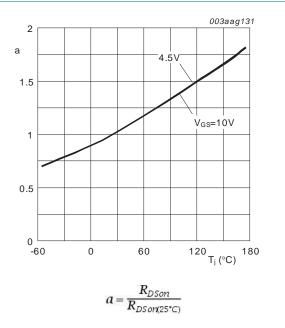


Fig 13. Normalized drain-source on-state resistance factor as a function of junction temperature

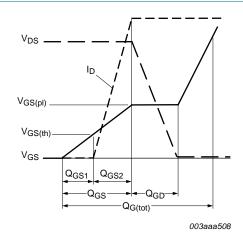
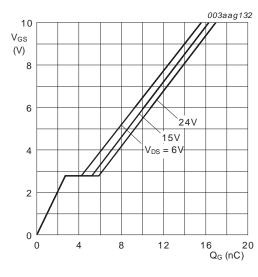


Fig 14. Gate charge waveform definitions



 $T_j = 25^{\circ}C; \ I_D = 20A$

Fig 15. Gate-source voltage as a function of gate charge; typical values

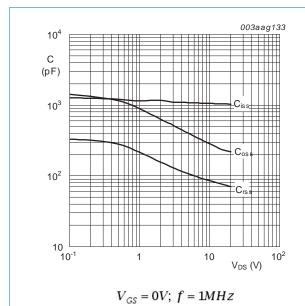


Fig 16. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

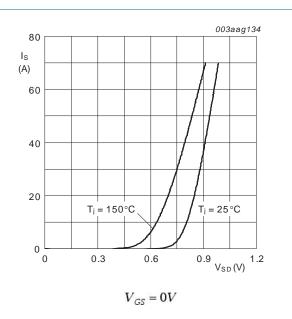


Fig 17. Source current as a function of source-drain voltage; typical values

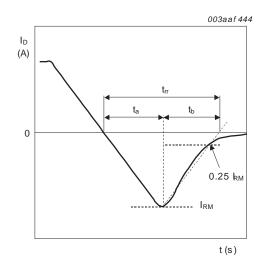
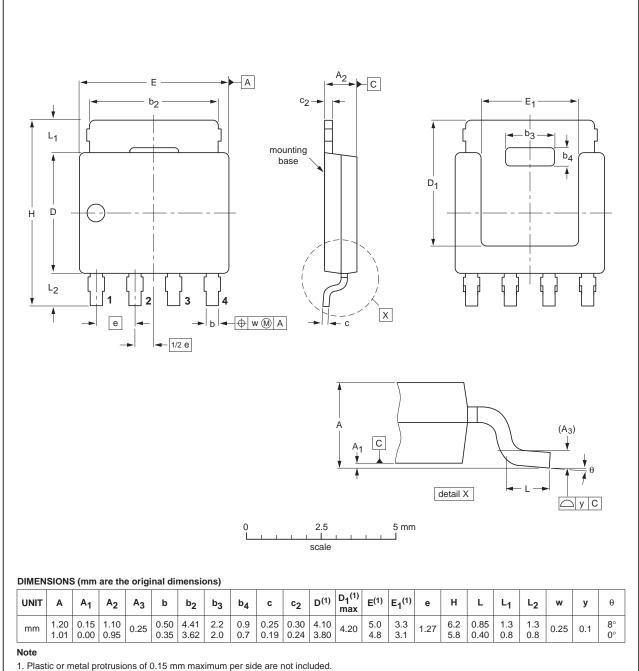


Fig 18. Reverse recovery timing definition

Package outline

Plastic single-ended surface-mounted package (LFPAK; Power-SO8); 4 leads

SOT669



OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT669		MO-235			06-03-16 11-03-25

Fig 19. Package outline SOT669 (LFPAK; Power-SO8)

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8. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PSMN7R0-30YLC v.2	20110901	Product data sheet	-	PSMN7R0-30YLC v.1
Modifications:	 Status changed from 	om objective to product.		
	 Various changes to 	content.		
PSMN7R0-30YLC v.1	20110711	Objective data sheet	-	-

Product data sheet

9. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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Product data sheet

PSMN7R0-30YLC

N-channel 30 V 7.1 m Ω logic level MOSFET in LFPAK using NextPower technology

11. Contents

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